

### Vishay Semiconductors

## High Performance Schottky Rectifier, 1.0 A



| PRODUCT SUMMARY                  |                |  |  |
|----------------------------------|----------------|--|--|
| Package                          | SMB            |  |  |
| I <sub>F(AV)</sub>               | 1.0 A          |  |  |
| V <sub>R</sub>                   | 40 V           |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.38 V         |  |  |
| I <sub>RM</sub>                  | 9 mA at 125 °C |  |  |
| T <sub>J</sub> max.              | 150 °C         |  |  |
| Diode variation                  | Single die     |  |  |
| E <sub>AS</sub>                  | 3.0 mJ         |  |  |

#### **FEATURES**





Guard ring for enhanced ruggedness and long term reliability

COMPLIANT HALOGEN FREE

- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

The VS-10BQ040-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |             |       |  |
|-----------------------------------|---|-------------|-------|--|
| SYMBOL                            | CHARACTERISTICS                               | VALUES      | UNITS |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                          | 1.0         | A     |  |
| $V_{RRM}$                         |   | 40          | V     |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                    | 430         | A     |  |
| V <sub>F</sub>                    | 1.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.38        | V     |  |
| $T_J$                             | Range   | -55 to +150 | °C    |  |

| VOLTAGE RATINGS                      |           |               |       |  |  |
|--------------------------------------|-----------|---------------|-------|--|--|
| PARAMETER                            | SYMBOL    | VS-10BQ040-M3 | UNITS |  |  |
| Maximum DC reverse voltage           | $V_{R}$   | 40            | V     |  |  |
| Maximum working peak reverse voltage | $V_{RWM}$ | 40            | V     |  |  |

| ABSOLUTE MAXIMUM RATINGS        |                    |  |                                |        |       |
|---------------------------------|--------------------|--|--------------------------------|--------|-------|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS  |                                | VALUES | UNITS |
| Maximum average forward current | I <sub>F(AV)</sub> | F(AV) 50 % duty cycle at T <sub>L</sub> = 122 °C, rectangular waveform   |                                | 1.0    | Α     |
| Maximum peak one cycle          | l                  | 5 μs sine or 3 μs rect. pulse  | Following any rated            | 430    | Α     |
| non-repetitive surge current    | I <sub>FSM</sub>   | 10 ms sine or 6 ms rect. pulse   | rated V <sub>RRM</sub> applied | 40     | A     |
| Non-repetitive avalanche energy | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH  |                                | 3.0    | mJ    |
| Repetitive avalanche current    | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical  1.0 |                                | А      |       |



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| ELECTRICAL SPECIFICATIONS       |                                |  |                                       |        |       |
|---------------------------------|--------------------------------|--|---------------------------------------|--------|-------|
| PARAMETER                       | SYMBOL                         | TEST CONDITIONS  |                                       | VALUES | UNITS |
|                                 | V (1)                          | 1 A  | T <sub>J</sub> = 25 °C                | 0.45   | V     |
| Maximum forward voltage drop    |                                | 2 A  |                                       | 0.52   |       |
| See fig. 1                      | V <sub>FM</sub> <sup>(1)</sup> | 1 A  | T <sub>J</sub> = 125 °C               | 0.38   |       |
|                                 |                                | 2 A  |                                       | 0.50   |       |
| Maximum reverse leakage current |                                | T <sub>J</sub> = 25 °C   | V <sub>R</sub> = Rated V <sub>R</sub> | 0.1    | - mA  |
| See fig. 2                      | I <sub>RM</sub>                | T <sub>J</sub> = 125 °C  | VR = nateu VR                         | 9.0    | IIIA  |
| Typical junction capacitance    | C <sub>T</sub>                 | $V_R = 5 V_{DC}$ , (test signal range 100 kHz to 1 MHz), 25 °C |                                       | 115    | pF    |
| Typical series inductance       | L <sub>S</sub>                 | Measured lead to lead 5 mm from package body                   |                                       | 2.0    | nΗ    |
| Maximum voltage rate of charge  | dV/dt                          | Rated V <sub>R</sub> 10 000                                    |                                       | V/µs   |       |

#### Note

 $<sup>^{(1)}</sup>$  Pulse width = 300  $\mu$ s, duty cycle = 2 %

| THERMAL - MECHANICAL SPECIFICATIONS             |  |                                   |             |       |
|---|--|-----------------------------------|-------------|-------|
| PARAMETER                                       | SYMBOL   | TEST CONDITIONS                   | VALUES      | UNITS |
| Maximum junction and storage temperature range  | T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub> |                                   | -55 to +150 | °C    |
| Maximum thermal resistance, junction to lead    | R <sub>thJL</sub> <sup>(2)</sup>                 | DC operation                      | 36          | °C/W  |
| Maximum thermal resistance, junction to ambient | R <sub>thJA</sub>                                |                                   | 80          | C/VV  |
| Approximate weight                              |  |                                   | 0.10        | g     |
| Approximate weight                              |  |                                   | 0.003       | oz.   |
| Marking device                                  |  | Case style SMB (similar DO-214AA) | 1           | F     |

#### Notes

<sup>(1)</sup>  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

<sup>(2)</sup> Mounted 1" square PCB

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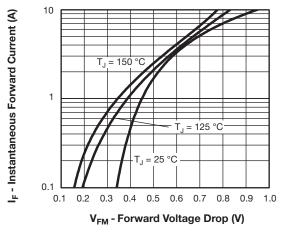


Fig. 1 - Maximum Forward Voltage Drop Characteristics

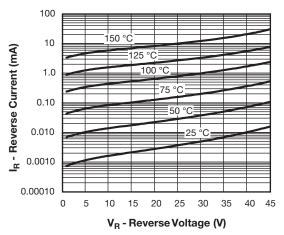


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

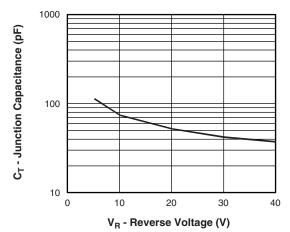


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

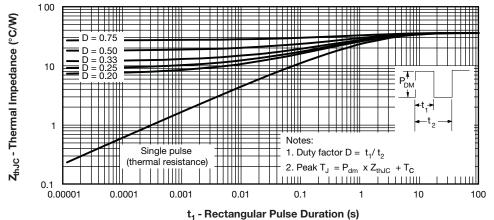


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



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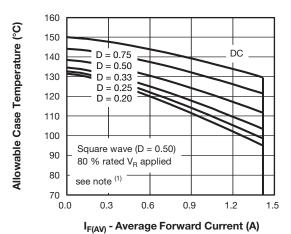


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

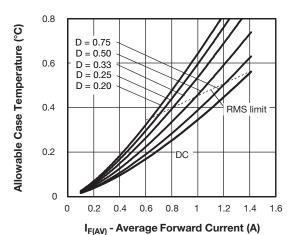


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

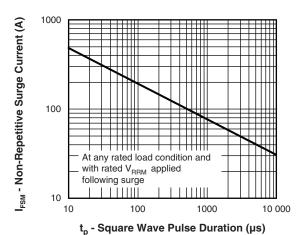


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

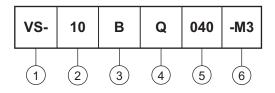
 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = 80 \ \% \ \text{rated } V_R \end{aligned}$ 



### Vishay Semiconductors

### **ORDERING INFORMATION TABLE**





Vishay Semiconductors product

2 - Current rating

3 - B = SMB

Q = Schottky "Q" series

5 - Voltage rating (040 = 40 V)

6 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) |                        |                       |                                    |  |  |
|--------------------------------|------------------------|-----------------------|------------------------------------|--|--|
| PREFERRED P/N                  | PREFERRED PACKAGE CODE | PACKAGING DESCRIPTION |                                    |  |  |
| VS-10BQ040-M3/5BT              | 5BT                    | 3200                  | 13" diameter plastic tape and reel |  |  |

| LINKS TO RELATED DOCUMENTS                               |  |  |  |
|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95401</u>               |  |  |  |
| Part marking information <u>www.vishay.com/doc?95403</u> |  |  |  |
| Packaging information <u>www.vishay.com/doc?95404</u>    |  |  |  |



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